### **BAT54SW**

## **Dual Series Schottky Barrier Diodes**

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

### **Features**

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 Volts (Typ) @  $I_F = 10 \text{ mAdc}$
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS (T<sub>J</sub> = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	30	V
Total Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Forward Current (DC)	lF	200	mA
Non-Repetitive Peak Forward Current t <sub>p</sub> < 10 msec	I <sub>FSM</sub>	600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I <sub>FRM</sub>	300	mA
Junction Temperature	TJ	-55 to 125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Electrostatic Discharge	ESD	HM < 8000 MM < 400	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



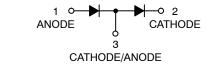
### ON Semiconductor®

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# 30 VOLT DUAL SERIES SCHOTTKY BARRIER DIODES



SOT-323 CASE 419 STYLE 9



### **MARKING DIAGRAM**



B8 = Device Code

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

Devi	се	Package	Shipping <sup>†</sup>
BAT54SW	Γ1G	SOT-323 (Pb-Free)	3,000 / Tape & Reel
NSVBAT54	ISWT1G	SOT-323 (Pb-Free)	3,000 / Tape & Reel

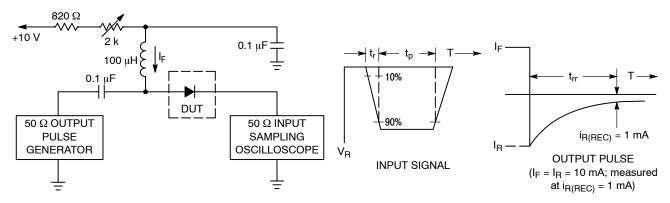
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **BAT54SW**

**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μA)	V <sub>(BR)R</sub>	30	-	-	V
Reverse Leakage (V <sub>R</sub> = 25 V)	I <sub>R</sub>	-	0.5	2.0	μΑ
Forward Voltage (I <sub>F</sub> = 0.1 mA) (I <sub>F</sub> = 1.0 mA) (I <sub>F</sub> = 10 mA) (I <sub>F</sub> = 30 mA) (I <sub>F</sub> = 100 mA)	V <sub>F</sub>	- - - -	0.22 0.29 0.35 0.41 0.52	0.24 0.32 0.40 0.5 0.8	V
Total Capacitance (V <sub>R</sub> = 1.0 V, f = 1.0 MHz)	C <sub>T</sub>	-	7.6	10	pF
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}, Figure 1)$	t <sub>rr</sub>	-	-	5.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA.

- 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA.
- 3. t<sub>p</sub> » t<sub>ri</sub>

Figure 1. Recovery Time Equivalent Test Circuit

### **BAT54SW**

### **TYPICAL CHARACTERISTICS**

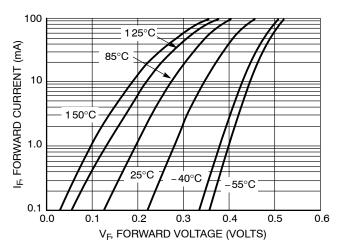


Figure 2. Forward Voltage

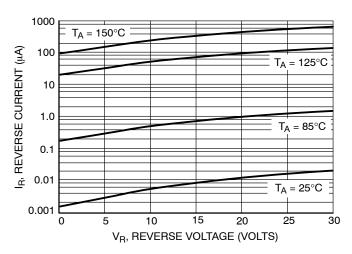


Figure 3. Leakage Current

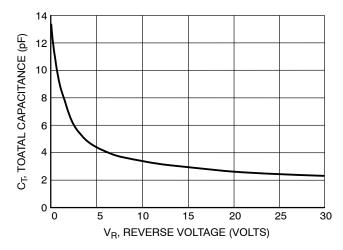


Figure 4. Total Capacitance





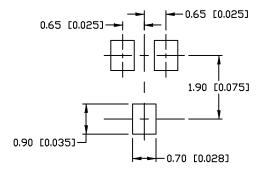
SC-70 (SOT-323) CASE 419 ISSUE P

**DATE 07 OCT 2021** 

### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS				INCHES	
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
۵	0.30	0.35	0.40	0.012	0.014	0.016
U	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2,20	0.071	0.083	0.087
ы	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC				0.026 BS	:C
اد	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



For additional information on our Pb-Free strategy and soldering details, please download the IIN Semiconductor Soldering and Mounting Techniques Reference Manual, SILDERRM/D.

SOLDERING FOOTPRINT

# TOP VIEW SIDE VIEW END VIEW

GENERIC MARKING DIAGRAM



XX = Specific Device Code

M = Date Code

■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	
CANCELLED	PIN 1. ANODE	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
	2. N.C.	2. EMITTER	2. CATHODE	2. ANODE	
	<ol><li>CATHODE</li></ol>	<ol><li>COLLECTOR</li></ol>	3. ANODE	<ol><li>CATHODE</li></ol>	
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:
PIN 1. EMITTER	PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	<ol><li>CATHODE</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>COLLECTOR</li></ol>	3. DRAIN	<ol><li>CATHODE-ANODE</li></ol>	3. ANODE-CATHODE	<ol><li>CATHODE</li></ol>

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DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1	

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